# NSN 5961-00-359-5752

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## **Inclosure Material:**

Metal

**Overall Length:** 

1.573 inches

# **Overall Height:**

0.380 inches

# **Overall Width:**

1.050 inches

## **Mounting Facility Quantity:**

2

#### **Internal Configuration:**

Junction contact

#### **Electrode Internally-electrically Connected To Case:**

Collector

#### **Mounting Method:**

Unthreaded hole

# **Features Provided:**

Hermetically sealed case

#### **Semiconductor Material:**

Silicon

#### Voltage Rating In Volts Per Characteristic:

150.0 collector to base voltage/static/emitter open and 90.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

Between 5.00 amperes source cutoff current and 20.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

140.0 watts small-signal input power, common-collector absolute

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

# **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

# **Specification Data:**

81349-mil-s-19500/439 government specification

# Shelf Life:

N/a

#### Unit Of Measure:

- **Demilitarization:**

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